# E·XFL

### NXP USA Inc. - KMPC8347VVAGDB Datasheet



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#### **Understanding Embedded - Microprocessors**

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

#### Applications of **Embedded - Microprocessors**

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

#### Details

Product Status	Obsolete
Core Processor	PowerPC e300
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	400MHz
Co-Processors/DSP	-
RAM Controllers	DDR
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (2)
SATA	-
USB	USB 2.0 + PHY (2)
Voltage - I/O	2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	672-LBGA
Supplier Device Package	672-LBGA (35x35)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/kmpc8347vvagdb

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#### Overview

- Up to four physical banks (chip selects), each bank up to 1 Gbyte independently addressable
- DRAM chip configurations from 64 Mbits to 1 Gbit with  $\times 8/\times 16$  data ports
- Full error checking and correction (ECC) support
- Support for up to 16 simultaneous open pages (up to 32 pages for DDR2)
- Contiguous or discontiguous memory mapping
- Read-modify-write support
- Sleep-mode support for SDRAM self refresh
- Auto refresh
- On-the-fly power management using CKE
- Registered DIMM support
- 2.5-V SSTL2 compatible I/O for DDR1, 1.8-V SSTL2 compatible I/O for DDR2
- Dual three-speed (10/100/1000) Ethernet controllers (TSECs)
  - Dual controllers designed to comply with IEEE 802.3<sup>TM</sup>, 802.3u<sup>TM</sup>, 820.3x<sup>TM</sup>, 802.3z<sup>TM</sup>, 802.3ac<sup>TM</sup> standards
  - Ethernet physical interfaces:
    - 1000 Mbps IEEE Std. 802.3 GMII/RGMII, IEEE Std. 802.3z TBI/RTBI, full-duplex
    - 10/100 Mbps IEEE Std. 802.3 MII full- and half-duplex
  - Buffer descriptors are backward-compatible with MPC8260 and MPC860T 10/100 programming models
  - 9.6-Kbyte jumbo frame support
  - RMON statistics support
  - Internal 2-Kbyte transmit and 2-Kbyte receive FIFOs per TSEC module
  - MII management interface for control and status
  - Programmable CRC generation and checking
- PCI interface
  - Designed to comply with PCI Specification Revision 2.3
  - Data bus width:
    - 32-bit data PCI interface operating at up to 66 MHz
  - PCI 3.3-V compatible
  - PCI host bridge capabilities
  - PCI agent mode on PCI interface
  - PCI-to-memory and memory-to-PCI streaming
  - Memory prefetching of PCI read accesses and support for delayed read transactions
  - Posting of processor-to-PCI and PCI-to-memory writes
  - On-chip arbitration supporting five masters on PCI
  - Accesses to all PCI address spaces
  - Parity supported
  - Selectable hardware-enforced coherency



Figure 3 shows the undershoot and overshoot voltage of the PCI interface of the MPC8347EA for the 3.3-V signals, respectively.



Figure 3. Maximum AC Waveforms on PCI Interface for 3.3-V Signaling

### 2.1.3 Output Driver Characteristics

Table 3 provides information on the characteristics of the output driver strengths. The values are preliminary estimates.

Driver Type	Output Impedance (Ω)	Supply Voltage
Local bus interface utilities signals	40	OV <sub>DD</sub> = 3.3 V
PCI signals (not including PCI output clocks)	25	
PCI output clocks (including PCI_SYNC_OUT)	40	
DDR signal	18	GV <sub>DD</sub> = 2.5 V
DDR2 signal	18 36 (half-strength mode)	GV <sub>DD</sub> = 1.8 V
TSEC/10/100 signals	40	LV <sub>DD</sub> = 2.5/3.3 V
DUART, system control, I <sup>2</sup> C, JTAG, USB	40	OV <sub>DD</sub> = 3.3 V
GPIO signals	40	OV <sub>DD</sub> = 3.3 V, LV <sub>DD</sub> = 2.5/3.3 V

Table 3. Output Drive Capability

### 2.2 **Power Sequencing**

This section details the power sequencing considerations for the MPC8347EA.

### 2.2.1 Power-Up Sequencing

MPC8347EAdoes not require the core supply voltage ( $V_{DD}$  and  $AV_{DD}$ ) and I/O supply voltages ( $GV_{DD}$ ,  $LV_{DD}$ , and  $OV_{DD}$ ) to be applied in any particular order. During the power ramp up, before the power

**Power Characteristics** 

	Core Frequency (MHz)	CSB Frequency (MHz)	Typical at T <sub>J</sub> = 65	Typical <sup>2,3</sup>	Maximum <sup>4</sup>	Unit
TBGA	333	333	2.0	3.0	3.2	W
		166	1.8	2.8	2.9	W
	400	266	2.1	3.0	3.3	W
		133	1.9	2.9	3.1	W
	450	300	2.3	3.2	3.5	W
		150	2.1	3.0	3.2	W
	500	333	2.4	3.3	3.6	W
		166	2.2	3.1	3.4	W
	533	266	2.4	3.3	3.6	W
		133	2.2	3.1	3.4	W
	667 <sup>5,6</sup>	333	3.5	4.6	5	W

 Table 4. MPC8347EA Power Dissipation<sup>1</sup> (continued)

<sup>1</sup> The values do not include I/O supply power (OV<sub>DD</sub>, LV<sub>DD</sub>, GV<sub>DD</sub>) or AV<sub>DD</sub>. For I/O power values, see Table 5.

<sup>2</sup> Typical power is based on a voltage of  $V_{DD} = 1.2$  V, a junction temperature of  $T_J = 105$  °C, and a Dhrystone benchmark application.

<sup>3</sup> Thermal solutions may need to design to a value higher than typical power based on the end application, T<sub>A</sub> target, and I/O power.

<sup>4</sup> Maximum power is based on a voltage of V<sub>DD</sub> = 1.2 V, worst case process, a junction temperature of T<sub>J</sub> = 105°C, and an artificial smoke test.

<sup>5</sup> Typical power is based on a voltage of  $V_{DD}$  = 1.3 V, a junction temperature of  $T_J$  = 105°C, and a Dhrystone benchmark application.

<sup>6</sup> Maximum power is based on a voltage of  $V_{DD}$  = 1.3 V, worst case process, a junction temperature of  $T_J$  = 105°C, and an artificial smoke test.



Table 5 shows the estimated typical I/O power dissipation for MPC8347EA.

Interface	Parameter	DDR2 GV <sub>DD</sub> (1.8 V)	DDR1 GV <sub>DD</sub> (2.5 V)	OV <sub>DD</sub> (3.3 V)	LV <sub>DD</sub> (3.3 V)	LV <sub>DD</sub> (2.5 V)	Unit	Comments
DDR I/O	200 MHz, 32 bits	0.31	0.42	—		_	W	—
65% utilization 2.5 V	200 MHz, 64 bits	0.42	0.55	—			W	—
Rs = 20 Ω Bt = 50 Ω	266 MHz, 32 bits	0.35	0.5	—		_	W	_
2 pair of clocks	266 MHz, 64 bits	0.47	0.66	—			W	—
	300 MHz, <sup>1</sup> 32 bits	0.37	0.54	—			W	—
	300 MHz, <sup>1</sup> 64 bits	0.50	0.7	—			W	—
	333 MHz, <sup>1</sup> 32 bits	0.39	0.58	—			W	—
	333 MHz, <sup>1</sup> 64 bits	0.53	0.76	—			W	—
	400 MHz, <sup>1</sup> 32 bits	0.44	_	—				—
	400 MHz, <sup>1</sup> 64 bits	0.59	—	_				—
PCI I/O	33 MHz, 32 bits	—	—	0.04			W	_
load = $30 \text{ pF}$	66 MHz, 32 bits	—	—	0.07			W	_
Local bus I/O	167 MHz, 32 bits	—	—	0.34	_	_	W	—
10ad = 25 pF	133 MHz, 32 bits	—	—	0.27	_	_	W	—
	83 MHz, 32 bits	—	—	0.17			W	_
	66 MHz, 32 bits	—	—	0.14			W	_
	50 MHz, 32 bits	—	—	0.11	_	_	W	—
TSEC I/O	MII	—	—	_	0.01	_	W	Multiply by number of
10ad = 25 pF	GMII or TBI	—	—	_	0.06	_	W	interfaces used.
	RGMII or RTBI	—	—	_	_	0.04	W	
USB	12 MHz	—	—	0.01			W	Multiply by 2 if using
	480 MHz	—	—	0.2			W	2 ports.
Other I/O		_	_	0.01	_	_	W	—

Table 5. MPC8347EA Typical I/O Power Dissipation

<sup>1</sup> TBGA package only.



DDR and DDR2 SDRAM

### Table 15 provides the DDR capacitance when $GV_{DD}(typ) = 2.5$ V.

### Table 15. DDR SDRAM Capacitance for GV<sub>DD</sub>(typ) = 2.5 V

Parameter/Condition	Symbol	Min	Max	Unit	Notes
Input/output capacitance: DQ, DQS	C <sub>IO</sub>	6	8	pF	1
Delta input/output capacitance: DQ, DQS	C <sub>DIO</sub>	_	0.5	pF	1

Note:

1. This parameter is sampled.  $GV_{DD} = 2.5 V \pm 0.125 V$ , f = 1 MHz,  $T_A = 25^{\circ}C$ ,  $V_{OUT} = GV_{DD}/2$ ,  $V_{OUT}$  (peak-to-peak) = 0.2 V.

### Table 16 provides the current draw characteristics for $MV_{REF}$ .

Table 16. Current Draw Characteristics for MV<sub>REF</sub>

Parameter/Condition	Symbol	Min	Max	Unit	Note
Current draw for MV <sub>REF</sub>	I <sub>MVREF</sub>		500	μA	1

#### Note:

1. The voltage regulator for  $\text{MV}_{\text{REF}}$  must supply up to 500  $\mu\text{A}$  current.

### 6.2 DDR and DDR2 SDRAM AC Electrical Characteristics

This section provides the AC electrical characteristics for the DDR and DDR2 SDRAM interface.

### 6.2.1 DDR and DDR2 SDRAM Input AC Timing Specifications

Table 17 provides the input AC timing specifications for the DDR2 SDRAM when  $GV_{DD}(typ) = 1.8 \text{ V}$ .

### Table 17. DDR2 SDRAM Input AC Timing Specifications for 1.8-V Interface

At recommended operating conditions with  $GV_{DD}$  of 1.8 ± 5%.

Parameter	Symbol	Min	Мах	Unit	Notes
AC input low voltage	V <sub>IL</sub>	_	MV <sub>REF</sub> – 0.25	V	_
AC input high voltage	V <sub>IH</sub>	MV <sub>REF</sub> + 0.25	_	V	_

Table 18 provides the input AC timing specifications for the DDR SDRAM when  $GV_{DD}(typ) = 2.5 \text{ V}$ .

### Table 18. DDR SDRAM Input AC Timing Specifications for 2.5-V Interface

At recommended operating conditions with  $GV_{DD}$  of 2.5 ± 5%.

Parameter	Symbol	Min	Мах	Unit	Notes
AC input low voltage	V <sub>IL</sub>	—	MV <sub>REF</sub> – 0.31	V	—
AC input high voltage	V <sub>IH</sub>	MV <sub>REF</sub> + 0.31	—	V	—



Parameter	Symbol	Min	Мах	Unit
High-level output voltage, $I_{OH} = -100 \ \mu A$	V <sub>OH</sub>	OV <sub>DD</sub> - 0.2	_	V
Low-level output voltage, $I_{OL} = 100 \ \mu A$	V <sub>OL</sub>	—	0.2	V

#### Table 21. DUART DC Electrical Characteristics (continued)

### 7.2 DUART AC Electrical Specifications

Table 22 provides the AC timing parameters for the DUART interface of the MPC8347EA.

**Table 22. DUART AC Timing Specifications** 

Parameter	Value	Unit	Notes
Minimum baud rate	256	baud	
Maximum baud rate	> 1,000,000	baud	1
Oversample rate	16		2

Notes:

1. Actual attainable baud rate will be limited by the latency of interrupt processing.

2. The middle of a start bit is detected as the 8<sup>th</sup> sampled 0 after the 1-to-0 transition of the start bit. Subsequent bit values are sampled each 16<sup>th</sup> sample.

## 8 Ethernet: Three-Speed Ethernet, MII Management

This section provides the AC and DC electrical characteristics for three-speeds (10/100/1000 Mbps) and MII management.

### 8.1 Three-Speed Ethernet Controller (TSEC)—GMII/MII/TBI/RGMII/RTBI Electrical Characteristics

The electrical characteristics specified here apply to gigabit media independent interface (GMII), the media independent interface (MII), ten-bit interface (TBI), reduced gigabit media independent interface (RGMII), and reduced ten-bit interface (RTBI) signals except management data input/output (MDIO) and management data clock (MDC). The MII, GMII, and TBI interfaces are defined for 3.3 V, and the RGMII and RTBI interfaces are defined for 2.5 V. The RGMII and RTBI interfaces follow the Hewlett-Packard *Reduced Pin-Count Interface for Gigabit Ethernet Physical Layer Device Specification*, Version 1.2a (9/22/2000). The electrical characteristics for MDIO and MDC are specified in Section 8.3, "Ethernet Management Interface Electrical Characteristics."



#### Table 27. MII Transmit AC Timing Specifications (continued)

At recommended operating conditions with LV<sub>DD</sub>/OV<sub>DD</sub> of 3.3 V  $\pm$  10%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Мах	Unit
TX_CLK data clock rise (20%-80%)	t <sub>MTXR</sub>	1.0	_	4.0	ns
TX_CLK data clock fall (80%-20%)	t <sub>MTXF</sub>	1.0	_	4.0	ns

### Note:

The symbols for timing specifications follow the pattern of t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t<sub>MTKHDX</sub> symbolizes MII transmit timing (MT) for the time t<sub>MTX</sub> clock reference (K) going high (H) until data outputs (D) are invalid (X). In general, the clock reference symbol is based on two to three letters representing the clock of a particular function. For example, the subscript of t<sub>MTX</sub> represents the MII(M) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
</sub></sub>

Figure 11 shows the MII transmit AC timing diagram.



Figure 11. MII Transmit AC Timing Diagram

### 8.2.2.2 MII Receive AC Timing Specifications

Table 28 provides the MII receive AC timing specifications.

#### Table 28. MII Receive AC Timing Specifications

At recommended operating conditions with  $LV_{DD}/OV_{DD}$  of 3.3 V ± 10%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Мах	Unit
RX_CLK clock period 10 Mbps	t <sub>MRX</sub>	_	400	—	ns
RX_CLK clock period 100 Mbps	t <sub>MRX</sub>	_	40	—	ns
RX_CLK duty cycle	t <sub>MRXH</sub> /t <sub>MRX</sub>	35	—	65	%
RXD[3:0], RX_DV, RX_ER setup time to RX_CLK	t <sub>MRDVKH</sub>	10.0	—	—	ns
RXD[3:0], RX_DV, RX_ER hold time to RX_CLK	t <sub>MRDXKH</sub>	10.0	—	—	ns



#### Ethernet: Three-Speed Ethernet, MII Management

#### Table 28. MII Receive AC Timing Specifications (continued)

At recommended operating conditions with  $LV_{DD}/OV_{DD}$  of 3.3 V  $\pm$  10%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Тур	Мах	Unit
RX_CLK clock rise (20%–80%)	t <sub>MRXR</sub>	1.0	—	4.0	ns
RX_CLK clock fall time (80%–20%)	t <sub>MRXF</sub>	1.0	—	4.0	ns

#### Note:

The symbols for timing specifications follow the pattern of t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. For example, t<sub>MRDVKH</sub> symbolizes MII receive timing (MR) with respect to the time data input signals (D) reach the valid state (V) relative to the t<sub>MRX</sub> clock reference (K) going to the high (H) state or setup time. Also, t<sub>MRDXKL</sub> symbolizes MII receive timing (CD) went invalid (X) relative to the t<sub>MRX</sub> clock reference (K) going to the low (L) state or hold time. In general, the clock reference symbol is based on three letters representing the clock of a particular function. For example, the subscript of t<sub>MRX</sub> represents the MII (M) receive (RX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
</sub>

Figure 12 provides the AC test load for TSEC.



Figure 12. TSEC AC Test Load

Figure 13 shows the MII receive AC timing diagram.



Figure 13. MII Receive AC Timing Diagram

### 8.2.3 TBI AC Timing Specifications

This section describes the TBI transmit and receive AC timing specifications.



### 10.2 Local Bus AC Electrical Specification

Table 38 and Table 39 describe the general timing parameters of the local bus interface of the MPC8347EA.

Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
Local bus cycle time	t <sub>LBK</sub>	7.5	—	ns	2
Input setup to local bus clock (except LUPWAIT)	t <sub>LBIVKH1</sub>	1.5	—	ns	3, 4
LUPWAIT input setup to local bus clock	t <sub>LBIVKH2</sub>	2.2	—	ns	3, 4
Input hold from local bus clock (except LUPWAIT)	t <sub>LBIXKH1</sub>	1.0	—	ns	3, 4
LUPWAIT Input hold from local bus clock	t <sub>LBIXKH2</sub>	1.0	—	ns	3, 4
LALE output fall to LAD output transition (LATCH hold time)	t <sub>LBOTOT1</sub>	1.5	—	ns	5
LALE output fall to LAD output transition (LATCH hold time)	t <sub>LBOTOT2</sub>	3	—	ns	6
LALE output fall to LAD output transition (LATCH hold time)	t <sub>LBOTOT3</sub>	2.5	—	ns	7
Local bus clock to LALE rise	t <sub>LBKHLR</sub>	—	4.5	ns	—
Local bus clock to output valid (except LAD/LDP and LALE)	t <sub>LBKHOV1</sub>	—	4.5	ns	—
Local bus clock to data valid for LAD/LDP	t <sub>LBKHOV2</sub>	—	4.5	ns	3
Local bus clock to address valid for LAD	t <sub>LBKHOV3</sub>	—	4.5	ns	3
Output hold from local bus clock (except LAD/LDP and LALE)	t <sub>LBKHOX1</sub>	1	—	ns	3
Output hold from local bus clock for LAD/LDP	t <sub>LBKHOX2</sub>	1	—	ns	3
Local bus clock to output high impedance for LAD/LDP	t <sub>LBKHOZ</sub>		3.8	ns	8

Table 38. Local Bus	General Timing	Parameters—DLL C	)n
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#### Notes:

 The symbols for timing specifications follow the pattern of t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. For example, t<sub>LBIXKH1</sub> symbolizes local bus timing (LB) for the input (I) to go invalid (X) with respect to the time the t<sub>LBK</sub> clock reference (K) goes high (H), in this case for clock one (1). Also, t<sub>LBKHOX</sub> symbolizes local bus timing (LB) for the t<sub>LBK</sub> clock reference (K) to go high (H), with respect to the output (O) going invalid (X) or output hold time.
</sub>

- 2. All timings are in reference to the rising edge of LSYNC\_IN.
- 3. All signals are measured from  $OV_{DD}/2$  of the rising edge of LSYNC\_IN to  $0.4 \times OV_{DD}$  of the signal in question for 3.3 V signaling levels.
- 4. Input timings are measured at the pin.
- 5. t<sub>LBOTOT1</sub> should be used when RCWH[LALE] is not set and when the load on the LALE output pin is at least 10 pF less than the load on the LAD output pins.
- t<sub>LBOTOT2</sub> should be used when RCWH[LALE] is set and when the load on the LALE output pin is at least 10 pF less than the load on the LAD output pins.
- 7. t<sub>LBOTOT3</sub> should be used when RCWH[LALE] is set and when the load on the LALE output pin equals the load on the LAD output pins.
- 8. For active/float timing measurements, the Hi-Z or off-state is defined to be when the total current delivered through the component pin is less than or equal to that of the leakage current specification.



I<sup>2</sup>C

# 12 I<sup>2</sup>C

This section describes the DC and AC electrical characteristics for the I<sup>2</sup>C interface of the MPC8347EA.

# **12.1** I<sup>2</sup>C DC Electrical Characteristics

Table 42 provides the DC electrical characteristics for the I<sup>2</sup>C interface of the MPC8347EA.

### Table 42. I<sup>2</sup>C DC Electrical Characteristics

At recommended operating conditions with  $\text{OV}_{\text{DD}}$  of 3.3 V  $\pm$  10%.

Parameter	Symbol	Min	Max	Unit	Notes
Input high voltage level	V <sub>IH</sub>	$0.7\times \text{OV}_{\text{DD}}$	OV <sub>DD</sub> + 0.3	V	—
Input low voltage level	V <sub>IL</sub>	-0.3	$0.3\times\text{OV}_{\text{DD}}$	V	—
Low level output voltage	V <sub>OL</sub>	0	$0.2\times \text{OV}_{\text{DD}}$	V	1
Output fall time from $V_{IH}$ (min) to $V_{IL}$ (max) with a bus capacitance from 10 to 400 pF	t <sub>i2KLKV</sub>	$20 + 0.1 \times C_B$	250	ns	2
Pulse width of spikes which must be suppressed by the input filter	t <sub>i2KHKL</sub>	0	50	ns	3
Input current each I/O pin (input voltage is between $0.1 \times OV_{DD}$ and $0.9 \times OV_{DD}$ (max)	I	-10	10	μA	4
Capacitance for each I/O pin	Cl	—	10	pF	_

Notes:

1. Output voltage (open drain or open collector) condition = 3 mA sink current.

2.  $C_B$  = capacitance of one bus line in pF.

3. Refer to the MPC8349EA Integrated Host Processor Family Reference Manual, for information on the digital filter used.

4. I/O pins obstruct the SDA and SCL lines if  $\ensuremath{\mathsf{OV}_{\mathsf{DD}}}$  is switched off.

# 12.2 I<sup>2</sup>C AC Electrical Specifications

Table 43 provides the AC timing parameters for the I<sup>2</sup>C interface of the MPC8347EA. Note that all values refer to  $V_{IH}(min)$  and  $V_{IL}(max)$  levels (see Table 42).

### Table 43. I<sup>2</sup>C AC Electrical Specifications

Parameter	Symbol <sup>1</sup>	Min	Max	Unit
SCL clock frequency	f <sub>I2C</sub>	0	400	kHz
Low period of the SCL clock	t <sub>I2CL</sub>	1.3	—	μs
High period of the SCL clock	t <sub>I2CH</sub>	0.6	—	μS
Setup time for a repeated START condition	t <sub>I2SVKH</sub>	0.6	—	μS
Hold time (repeated) START condition (after this period, the first clock pulse is generated)	t <sub>I2SXKL</sub>	0.6	-	μs
Data setup time	t <sub>I2DVKH</sub>	100	—	ns
Data hold time:CBUS compatible masters I <sup>2</sup> C bus devices	t <sub>I2DXKL</sub>	$\overline{0^2}$		μS



Package and Pin Listings

Figure 38 and Figure 39 represent the AC timings from Table 54. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.

Figure 38 shows the SPI timings in slave mode (external clock).



Note: The clock edge is selectable on SPI.

### Figure 38. SPI AC Timing in Slave Mode (External Clock) Diagram

Figure 39 shows the SPI timings in master mode (internal clock).



Note: The clock edge is selectable on SPI.



# **18 Package and Pin Listings**

This section details package parameters, pin assignments, and dimensions. The MPC8347EA is available in two packages—a tape ball grid array (TBGA) and a plastic ball grid array (PBGA). See Section 18.1, "Package Parameters for the MPC8347EA TBGA," Section 18.2, "Mechanical Dimensions for the MPC8347EA TBGA," Section 18.3, "Package Parameters for the MPC8347EA PBGA," and Section 18.4, "Mechanical Dimensions for the MPC8347EA PBGA."

### 18.1 Package Parameters for the MPC8347EA TBGA

The package parameters are provided in the following list. The package type is  $35 \text{ mm} \times 35 \text{ mm}$ , 672 tape ball grid array (TBGA).

Package outline	$35 \text{ mm} \times 35 \text{ mm}$
Interconnects	672



Package and Pin Listings

Table 55 MPC8347FA		) Pinout Listing	(continued)
TADIE JJ. IVIF COJ4/ LA	TDGA	/ Fillout Listing	(continueu)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
LALE	AK24	0	OV <sub>DD</sub>	
LGPL0/LSDA10/cfg_reset_source0	AP27	I/O	OV <sub>DD</sub>	
LGPL1/LSDWE/cfg_reset_source1	AL25	I/O	OV <sub>DD</sub>	_
LGPL2/LSDRAS/LOE	AJ24	0	OV <sub>DD</sub>	
LGPL3/LSDCAS/cfg_reset_source2	AN27	I/O	OV <sub>DD</sub>	_
LGPL4/LGTA/LUPWAIT/LPBSE	AP28	I/O	OV <sub>DD</sub>	13
LGPL5/cfg_clkin_div	AL26	I/O	OV <sub>DD</sub>	_
LCKE	AM27	0	OV <sub>DD</sub>	
LCLK[0:2]	AN28, AK26, AP29	0	OV <sub>DD</sub>	
LSYNC_OUT	AM12	0	OV <sub>DD</sub>	_
LSYNC_IN	AJ10	I	OV <sub>DD</sub>	
	General Purpose I/O Timers			
GPIO1[0]/DMA_DREQ0/GTM1_TIN1/ GTM2_TIN2	F24	I/O	OV <sub>DD</sub>	—
GPIO1[1]/DMA_DACK0/GTM1_TGATE1/ GTM2_TGATE2	E24	I/O	OV <sub>DD</sub>	_
GPIO1[2]/DMA_DDONE0/GTM1_TOUT1	B25	I/O	OV <sub>DD</sub>	_
GPIO1[3]/DMA_DREQ1/GTM1_TIN2/ GTM2_TIN1	D24	I/O	OV <sub>DD</sub>	_
GPIO1[4]/DMA_DACK1/GTM1_TGATE2/ GTM2_TGATE1	A25	I/O	OV <sub>DD</sub>	_
GPIO1[5]/DMA_DDONE1/GTM1_TOUT2/ GTM2_TOUT1	B24	I/O	OV <sub>DD</sub>	_
GPIO1[6]/DMA_DREQ2/GTM1_TIN3/ GTM2_TIN4	A24	I/O	OV <sub>DD</sub>	_
GPIO1[7]/DMA_DACK2/GTM1_TGATE3/ GTM2_TGATE4	D23	I/O	OV <sub>DD</sub>	_
GPIO1[8]/DMA_DDONE2/GTM1_TOUT3	B23	I/O	OV <sub>DD</sub>	
GPIO1[9]/DMA_DREQ3/GTM1_TIN4/ GTM2_TIN3	A23	I/O	OV <sub>DD</sub>	_
GPIO1[10]/DMA_DACK3/GTM1_TGATE4/ GTM2_TGATE3	F22	I/O	OV <sub>DD</sub>	_
GPIO1[11]/DMA_DDONE3/GTM1_TOUT4/ GTM2_TOUT3	E22	I/O	OV <sub>DD</sub>	_
	USB Port 1	1		
MPH1_D0_ENABLEN/DR_D0_ENABLEN	A26	I/O	OV <sub>DD</sub>	_
MPH1_D1_SER_TXD/DR_D1_SER_TXD	B26	I/O	OV <sub>DD</sub>	—
MPH1_D2_VMO_SE0/DR_D2_VMO_SE0	D25	I/O	OV <sub>DD</sub>	—



Package and Pin Listings

### Table 55. MPC8347EA (TBGA) Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
MPH1_D3_SPEED/DR_D3_SPEED	A27	I/O	OV <sub>DD</sub>	
MPH1_D4_DP/DR_D4_DP	B27	I/O	OV <sub>DD</sub>	_
MPH1_D5_DM/DR_D5_DM	C27	I/O	OV <sub>DD</sub>	—
MPH1_D6_SER_RCV/DR_D6_SER_RCV	D26	I/O	OV <sub>DD</sub>	—
MPH1_D7_DRVVBUS/DR_D7_DRVVBUS	E26	I/O	OV <sub>DD</sub>	—
MPH1_NXT/DR_SESS_VLD_NXT	D27	I	OV <sub>DD</sub>	—
MPH1_DIR_DPPULLUP/ DR_XCVR_SEL_DPPULLUP	A28	I/O	OV <sub>DD</sub>	—
MPH1_STP_SUSPEND/ DR_STP_SUSPEND	F26	0	OV <sub>DD</sub>	—
MPH1_PWRFAULT/ DR_RX_ERROR_PWRFAULT	E27	I	OV <sub>DD</sub>	—
MPH1_PCTL0/DR_TX_VALID_PCTL0	A29	0	OV <sub>DD</sub>	—
MPH1_PCTL1/DR_TX_VALIDH_PCTL1	D28	0	OV <sub>DD</sub>	—
MPH1_CLK/DR_CLK	B29	I	OV <sub>DD</sub>	—
	USB Port 0			
MPH0_D0_ENABLEN/DR_D8_CHGVBUS	C29	I/O	OV <sub>DD</sub>	—
MPH0_D1_SER_TXD/DR_D9_DCHGVBUS	A30	I/O	OV <sub>DD</sub>	—
MPH0_D2_VMO_SE0/DR_D10_DPPD	E28	I/O	OV <sub>DD</sub>	—
MPH0_D3_SPEED/DR_D11_DMMD	B30	I/O	OV <sub>DD</sub>	—
MPH0_D4_DP/DR_D12_VBUS_VLD	C30	I/O	OV <sub>DD</sub>	—
MPH0_D5_DM/DR_D13_SESS_END	A31	I/O	OV <sub>DD</sub>	—
MPH0_D6_SER_RCV/DR_D14	B31	I/O	OV <sub>DD</sub>	—
MPH0_D7_DRVVBUS/DR_D15_IDPULLUP	C31	I/O	OV <sub>DD</sub>	—
MPH0_NXT/DR_RX_ACTIVE_ID	B32	I	OV <sub>DD</sub>	—
MPH0_DIR_DPPULLUP/DR_RESET	A32	I/O	OV <sub>DD</sub>	—
MPH0_STP_SUSPEND/DR_TX_READY	A33	I/O	OV <sub>DD</sub>	—
MPH0_PWRFAULT/DR_RX_VALIDH	C32	I	OV <sub>DD</sub>	—
MPH0_PCTL0/DR_LINE_STATE0	D31	I/O	OV <sub>DD</sub>	—
MPH0_PCTL1/DR_LINE_STATE1	E30	I/O	OV <sub>DD</sub>	—
MPH0_CLK/DR_RX_VALID	B33	I	OV <sub>DD</sub>	—
Pr	ogrammable Interrupt Controller			
MCP_OUT	AN33	0	OV <sub>DD</sub>	2
IRQ0/MCP_IN/GPIO2[12]	C19	I/O	OV <sub>DD</sub>	
IRQ[1:5]/GPIO2[13:17]	C22, A22, D21, C21, B21	I/O	OV <sub>DD</sub>	



Package and Pin Listings

Signal	Package Pin Number	Pin Type	Power Supply	Notes
GV <sub>DD</sub>	A2, E2, G5, G6, J5, K4, K5, L4, N4, P5, R6, T6, U5, V1, W5, Y5, AA4, AB3, AC4, AD5, AF3, AG5, AH2, AH5, AH6, AJ6, AK6, AK8, AK9, AL6	Power for DDR DRAM I/O voltage (2.5 V)	GV <sub>DD</sub>	
LV <sub>DD</sub> 1	C9, D11	Power for three-speed Ethernet #1 and for Ethernet management interface I/O (2.5 V, 3.3 V)	LV <sub>DD</sub> 1	_
LV <sub>DD</sub> 2	C6, D9	Power for three-speed Ethernet #2 I/O (2.5 V, 3.3 V)	LV <sub>DD</sub> 2	
V <sub>DD</sub>	E19, E29, F7, F9, F11,F13, F15, F17, F18, F21, F23, F25, F29, H29, J6, K29, M29, N6, P29, T29, U30, V6, V29, W29, AB29, AC5, AD29, AF6, AF29, AH29, AJ8, AJ12, AJ14, AJ16, AJ18, AJ20, AJ21, AJ23, AJ25, AJ26, AJ27, AJ28, AJ29, AK10	Power for core (1.2 V nominal, 1.3 V for 667 MHz)	V <sub>DD</sub>	_
OV <sub>DD</sub>	B22, B28, C16, C17, C24, C26, D13, D15, D19, D29, E31, F28, G33, H30, L29, L32, N32, P31, R31, U32, W31, Y29, AA29, AC30, AE31, AF30, AG29, AJ17, AJ30, AK11, AL15, AL19, AL21, AL29, AL30, AM20, AM23, AM24, AM26, AM28, AN11, AN13	PCI, 10/100 Ethernet, and other standard (3.3 V)	OV <sub>DD</sub>	_
MVREF1	M3	I	DDR reference voltage	_
MVREF2	AD2	I	DDR reference voltage	

### Table 55. MPC8347EA (TBGA) Pinout Listing (continued)



- <sup>3</sup> The DDR data rate is 2× the DDR memory bus frequency.
- <sup>4</sup> The local bus frequency is ½, ¼, or 1/8 of the *lbiu\_clk* frequency (depending on LCCR[CLKDIV]) which is in turn 1× or 2× the *csb\_clk* frequency (depending on RCWL[LBIUCM]).

### 19.1 System PLL Configuration

The system PLL is controlled by the RCWL[SPMF] parameter. Table 60 shows the multiplication factor encodings for the system PLL.

RCWL[SPMF]	System PLL Multiplication Factor			
0000	× 16			
0001	Reserved			
0010	× 2			
0011	× 3			
0100	× 4			
0101	× 5			
0110	× 6			
0111	× 7			
1000	× 8			
1001	× 9			
1010	× 10			
1011	× 11			
1100	× 12			
1101	× 13			
1110	× 14			
1111	× 15			

 Table 60. System PLL Multiplication Factors

As described in Section 19, "Clocking," the LBIUCM, DDRCM, and SPMF parameters in the reset configuration word low and the CFG\_CLKIN\_DIV configuration input signal select the ratio between the primary clock input (CLKIN or PCI\_CLK) and the internal coherent system bus clock (*csb\_clk*). Table 61

			Input Clock Frequency (MHz) <sup>2</sup>			;) <sup>2</sup>
CFG_CLKIN_DIV at Reset <sup>1</sup>	SPMF	<i>csb_clk</i> : Input Clock Ratio <sup>2</sup>	16.67	25	33.33	66.67
				<i>csb_clk</i> Freq	uency (MHz)	
Low	0010	2 : 1				133
Low	0011	3 : 1			100	200
Low	0100	4 : 1		100	133	266
Low	0101	5 : 1		125	166	333
Low	0110	6 : 1	100	150	200	
Low	0111	7:1	116	175	233	
Low	1000	8:1	133	200	266	
Low	1001	9:1	150	225	300	
Low	1010	10 : 1	166	250	333	
Low	1011	11 : 1	183	275		
Low	1100	12 : 1	200	300		
Low	1101	13 : 1	216	325		
Low	1110	14 : 1	233			
Low	1111	15 : 1	250			
Low	0000	16 : 1	266			
High	0010	4 : 1		100	133	266
High	0011	6 : 1	100	150	200	
High	0100	8 : 1	133	200	266	
High	0101	10 : 1	166	250	333	
High	0110	12 : 1	200	300		
High	0111	14 : 1	233			
High	1000	16 : 1	266	1		

### Table 62. CSB Frequency Options for Agent Mode

<sup>1</sup> CFG\_CLKIN\_DIV doubles csb\_clk if set high.

<sup>2</sup> CLKIN is the input clock in host mode; PCI\_CLK is the input clock in agent mode.

DDR2 memory may be used at 133 MHz provided that the memory components are specified for operation at this frequency.

### 19.2 Core PLL Configuration

RCWL[COREPLL] selects the ratio between the internal coherent system bus clock (*csb\_clk*) and the e300 core clock (*core\_clk*). Table 63 shows the encodings for RCWL[COREPLL]. COREPLL values that are not listed in Table 63 should be considered as reserved.

### NOTE

Core VCO frequency = core frequency  $\times$  VCO divider



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The Bergquist Company 18930 West 78th St. Chanhassen, MN 55317 Internet: www.bergquistcompany.com 888-642-7674

800-347-4572

### 20.3 Heat Sink Attachment

When heat sinks are attached, an interface material is required, preferably thermal grease and a spring clip. The spring clip should connect to the printed-circuit board, either to the board itself, to hooks soldered to the board, or to a plastic stiffener. Avoid attachment forces that can lift the edge of the package or peel the package from the board. Such peeling forces reduce the solder joint lifetime of the package. The recommended maximum force on the top of the package is 10 lb force (4.5 kg force). Any adhesive attachment should attach to painted or plastic surfaces, and its performance should be verified under the application requirements.

# 20.3.1 Experimental Determination of the Junction Temperature with a Heat Sink

When a heat sink is used, the junction temperature is determined from a thermocouple inserted at the interface between the case of the package and the interface material. A clearance slot or hole is normally required in the heat sink. Minimize the size of the clearance to minimize the change in thermal performance caused by removing part of the thermal interface to the heat sink. Because of the experimental difficulties with this technique, many engineers measure the heat sink temperature and then back calculate the case temperature using a separate measurement of the thermal resistance of the interface. From this case temperature, the junction temperature is determined from the junction-to-case thermal resistance.

$$T_J = T_C + (R_{\theta JC} \times P_D)$$

where:

 $T_J$  = junction temperature (°C)  $T_C$  = case temperature of the package (°C)  $R_{\partial JC}$  = junction-to-case thermal resistance (°C/W)  $P_D$  = power dissipation (W)



#### System Design Information

capacitive loads. This noise must be prevented from reaching other components in the MPC8347EA system, and the device itself requires a clean, tightly regulated source of power. Therefore, the system designer should place at least one decoupling capacitor at each  $V_{DD}$ ,  $OV_{DD}$ ,  $GV_{DD}$ , and  $LV_{DD}$  pin of the device. These capacitors should receive their power from separate  $V_{DD}$ ,  $OV_{DD}$ ,  $GV_{DD}$ ,  $LV_{DD}$ , and GND power planes in the PCB, with short traces to minimize inductance. Capacitors can be placed directly under the device using a standard escape pattern. Others can surround the part.

These capacitors should have a value of 0.01 or 0.1  $\mu$ F. Only ceramic SMT (surface mount technology) capacitors should be used to minimize lead inductance, preferably 0402 or 0603 sizes.

In addition, distribute several bulk storage capacitors around the PCB, feeding the  $V_{DD}$ ,  $OV_{DD}$ ,  $GV_{DD}$ , and  $LV_{DD}$  planes, to enable quick recharging of the smaller chip capacitors. These bulk capacitors should have a low ESR (equivalent series resistance) rating to ensure the quick response time. They should also be connected to the power and ground planes through two vias to minimize inductance. Suggested bulk capacitors are 100–330  $\mu$ F (AVX TPS tantalum or Sanyo OSCON).

### 21.4 Connection Recommendations

To ensure reliable operation, connect unused inputs to an appropriate signal level. Unused active low inputs should be tied to  $OV_{DD}$ ,  $GV_{DD}$ , or  $LV_{DD}$  as required. Unused active high inputs should be connected to GND. All NC (no-connect) signals must remain unconnected.

Power and ground connections must be made to all external  $V_{DD}$ ,  $GV_{DD}$ ,  $LV_{DD}$ ,  $OV_{DD}$ , and GND pins of the MPC8347EA.

### 21.5 Output Buffer DC Impedance

The MPC8347EA drivers are characterized over process, voltage, and temperature. For all buses, the driver is a push-pull single-ended driver type (open drain for  $I^2C$ ).

To measure  $Z_0$  for the single-ended drivers, an external resistor is connected from the chip pad to  $OV_{DD}$  or GND. Then the value of each resistor is varied until the pad voltage is  $OV_{DD}/2$  (see Figure 44). The output impedance is the average of two components, the resistances of the pull-up and pull-down devices. When data is held high, SW1 is closed (SW2 is open) and R<sub>P</sub> is trimmed until the voltage at the pad equals



Document Revision History

### 22.2 Part Marking

Parts are marked as in the example shown in Figure 45.



Notes:

ATWLYYWW is the traceability code. CCCCC is the country code. MMMMM is the mask number. YWWLAZ is the assembly traceability code.

Figure 45. Freescale Part Marking for TBGA or PBGA Devices

# 23 Document Revision History

This table provides a revision history of this document.

Table 72	. Document	Revision	History
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Rev. Number	Date	Substantive Change(s)	
12	09/2011	<ul> <li>In Section 2.2, "Power Sequencing," added Section 2.2.1, "Power-Up Sequencing" and Figure 4.</li> <li>In Table 25, Table 29 and Table 31, removed the GTX_CLK125.</li> <li>In Table 34, updated t<sub>MDKHDX</sub> Max value from 170ns to 70ns.</li> </ul>	
11	11/2010	<ul> <li>In Table 56, added overbar to LCS[4] and LCS[5] signals. In Table 55 and Table 56, added note for pin LGPL4.</li> <li>In Section 21.7, "Pull-Up Resistor Requirements, updated the list of open drain type pins.</li> </ul>	
10	05/2010	<ul> <li>In Table 25 through Table 30, changed V<sub>IL</sub>(min) to V<sub>IH</sub>(max) to (20%–80%).</li> <li>Added Table 8, "EC_GTX_CLK125 AC Timing Specifications."</li> </ul>	
9	5/2009	<ul> <li>In Section 18.3, "Package Parameters for the MPC8347EA PBGA, changed solder ball for TBGA and PBGA from 95.5 Sn/0.5 Cu/4 Ag to 96.5 Sn/3.5 Ag.</li> <li>In Table 58, updated frequency for DDR2, from 100-200 to 100-133 at core frequency = 533MHz.</li> <li>In Table 59, added two columns for the DDR1 and DDR2 memory bus frequency.</li> <li>In Table 70, footnote 1, changed 667(TBGA) to 533(TBGA). footnote 4, added data rate for DDR1 and DDR2.</li> </ul>	



Table 72. Document Revision Histor	y i	(continued)
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Rev. Number	Date	Substantive Change(s)	
8	2/2009	<ul> <li>Added footnote 6 to Table 7.</li> <li>In Section 9.2, "USB AC Electrical Specifications," clarified that AC table is for ULPI only.</li> <li>In Table 39, corrected t<sub>LBKHOV</sub> parameter to t<sub>LBKLOV</sub> (output data is driven on falling edge of clock in DLL bypass mode). Similarly, made the same correction to Figure 22, Figure 24, and Figure 25 for output signals.</li> <li>Added footnote 10 and 11 to Table 55 and Table 56.</li> <li>In Section 21.1, "System Clocking," removed "(AVDD1)" and "(AVDD2") from bulleted list.</li> <li>In Section 21.2, "PLL Power Supply Filtering," in the second paragraph, changed "provide five independent filter circuits," and "the five AVDD pins" to provide four independent filter circuits," and "the four AVDD pins."</li> <li>In Table 58, corrected the max csb_clk to 266 MHz.</li> <li>In Table 64, added PLL configurations 903, 923, A03, A23, and 503 for 533 MHz</li> <li>Added footnote 4 to Table 70.</li> <li>In Table 70, updated note 1 to say the following: "For temperature range = C, processor frequency is limited to 533 (TBGA) and 400 (PBGA) with a platform frequency of 266."</li> </ul>	
7	4/2007	<ul> <li>In Table 3, "Output Drive Capability," changed the values in the Output Impedance column and added USB to the seventh row.</li> <li>In Table 4, "Operating Frequencies for TBGA," added column for 400 MHz.</li> <li>In Section 21.7, "Pull-Up Resistor Requirements, "deleted last two paragraphs and after first paragraph, added a new paragraph.</li> <li>Deleted Section 21.8, "JTAG Configuration Signals," and Figure 43, "JTAG Interface Connection."</li> </ul>	
6	3/2007	<ul> <li>Page 1, updated first paragraph to reflect PowerQUICC II Pro information.</li> <li>In Table 18, "DDR and DDR2 SDRAM Input AC Timing Specifications," added note 2 to t<sub>CISKEW</sub> and deleted original note 3; renumbered the remaining notes.</li> <li>In Figure 43, "JTAG Interface Connection," updated with new figure.</li> <li>In Table 57, "Operating Frequencies for TBGA," in the 'Coherent system bus frequency (<i>csb_clk</i>)' row, changed the value in the 533 MHz column to 100-333.</li> <li>In Table 63, "Suggested PLL Configurations," under the subhead, '33 MHz CLKIN/PCI_CLK Options,' added row A03 between Ref. No. 724 and 804. Under the subhead '66 MHz CLKIN/PCI_CLK Options,' added row 503 between Ref. No. 305 and 404. For Ref. No. 306, changed the CORE PLL value to 0000110.</li> <li>In Section 23, "Ordering Information," replaced first paragraph and added a note.</li> <li>In Section 23.1, "Part Numbers Fully Addressed by this Document," replaced first paragraph.</li> </ul>	
5	1/2007	<ul> <li>In Table 1, "Absolute Maximum Ratings," added (1.36 max for 667-MHz core frequency).</li> <li>In Table 2, "Recommended Operating Conditions," added a row showing nominal core supply voltage of 1.3 V for 667-MHz parts.</li> <li>In Table 4, "MPC8347EA Power Dissipation," added two footnotes to 667-MHz row showing nominal core supply voltage of 1.3 V for 667-MHz parts.</li> <li>In Table 54, "MPC8347EA (TBGA) Pinout Listing," updated V<sub>DD</sub> row to show nominal core supply voltage of 1.3 V for 667-MHz parts.</li> </ul>	
4	12/2006	Table 19, "DDR and DDR2 SDRAM Output AC Timing Specifications," modified T <sub>ddkhds</sub> for 333 MHz from 900 ps to 775 ps.	
3	11/2006	<ul> <li>Updated note in introduction.</li> <li>In the features list in Section 1, "Overview," updated DDR data rate to show 266 MHz for PBGA parts for all silicon revisions, and 400 MHz for DDR2 for TBGA parts for silicon Rev. 2 and 3.</li> <li>In Table 5, "MPC8347EA Typical I/O Power Dissipation," added GV<sub>DD</sub> 1.8-V values for DDR2; added table footnote to designate rates that apply only to the TBGA package.</li> <li>In Section 23, "Ordering Information," replicated note from document introduction.</li> </ul>	